

Electrochemical Studies of Guanosine in DMF and Detection of Its Radical Cation in a Scanning Electrochemical Microscopy Nanogap Experiment

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We report the electrochemical oxidation of guanosine (Gs) and the application of scanning electrochemical microscopy (SECM) in a nanogap configuration to detect and measure the lifetime of the Gs radical cation, Gs^{•+}. Gs is an important nucleoside^{1,2} because oxidation of the base guanine to the radical cation has been implicated in the transfer of charge and in radiative damage of DNA.³ The potential for Gs oxidation has been estimated by techniques, such as ionizing radiation, chemical oxidation, two-photon photoionization by a high-intensity laser pulse, and photoirradiation in the presence of photosensitizers.^{4–7} However, direct electrochemical measurement of the potential has been thwarted by the instability of Gs^{•+} and distortions of the voltammetric waves in water because of adsorption of Gs or its products.^{8,9} We show here that the oxidation of Gs in *N,N*-dimethylformamide (DMF) yields a nearly steady-state cyclic voltammogram (CV) of Gs at a carbon-fiber ultramicroelectrode (CF-UME), which is a requirement for kinetic studies by SECM. SECM, a powerful tool for studying fast heterogeneous and homogeneous electron-transfer reactions,^{10,11} with CF-UMEs was used in the feedback mode and in the generation/collection (G/C) mode in a nanogap configuration to detect the Gs^{•+} directly.

The EC oxidation of Gs at a CF-UME in various aqueous solutions at different pH values did not yield normal “S-shaped” steady-state CVs (see Supporting Information Figure S1). These results, similar to those observed at carbon macroelectrodes,^{12–14} suggest that Gs is adsorbed strongly at the CF-UME in aqueous solutions. Because of the adsorption problems encountered in aqueous solutions, DMF was used to study the EC oxidation of Gs. As a comparison with aqueous solution, we also added a small amount of an aqueous solution of 1.2 M H₃PO₄ to adjust the solution pH from that of dry DMF (11.85) to pH 7.10 (0.1% 1.2 M H₃PO₄) and pH 4.23 (3.5% 1.2 M H₃PO₄). The pH value was measured with an Orion Research model 70/A-digital ionalyzer (Cambridge, MA). Commercially available highest grade dry DMF contains ~0.002% of water. Thus, the DMF solutions of the three pH values (pH 11.85, 7.10, and 4.23) contained about 1.1 mM, 56 mM, and 1.94 M water, respectively. As shown in Figure 1, the EC oxidation of Gs at a CF-UME in DMF/0.1 M TBAPF₆ yielded a well-defined “S-shaped” steady-state CV with a half-wave potential, *E*_{1/2}, of 1.3 V versus a Ag quasireference electrode (AgQRE). The potential of the AgQRE was –0.43 V versus the *E*^o of ferrocene/ferrocenium (Fc/Fc⁺) couple in DMF. At a given sweep rate, *v*, the steady-state current, *i*_{ss}, depended linearly on the concentration of Gs (Figure S2). Also, at Gs concentrations ≤ 10 mM, the current response of Gs increased with increasing *v*^{1/2} at high *v* values, indicating a diffusion-controlled process (Figures S3 and S4). However, adsorption of Gs on the CF-UME in DMF occurred when the Gs concentration was > 10 mM, especially when the water content was high.

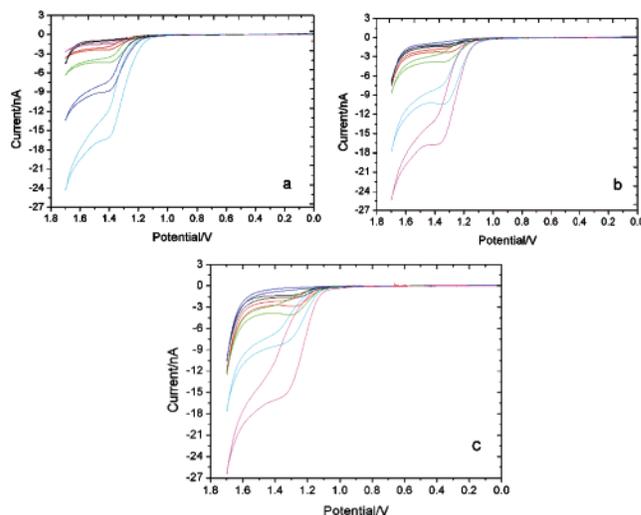


Figure 1. Plot of *i*_{ss} vs *C*_{Gs}^{*} at three different water contents in DMF with different pH values at the CF-UME (8- μ m diameter) in DMF/0.1 M TBAPF₆ solutions. (a) Dry DMF (pH 11.85). From bottom to top: 10, 5, 2, 1, 0.5, 0 mM. (b) 0.1% 1.2 M H₃PO₄ (pH 7.10). From bottom to top: 10, 5, 2, 1, 0.5, 0 mM. (c) 3.5% 1.2 M H₃PO₄ (pH 4.23). From bottom to top: 10, 5, 2, 1, 0.5, 0 mM. Scan rate, 20 mV/s.

Chronoamperometry was used to determine the number, *n*, of electrons involved in the first oxidation wave and the diffusion coefficient, *D*_{Gs}, of Gs in DMF with a Pt-UME of radius, *a*, of 12.5 μ m based on comparing the transient and steady-state currents.¹⁵ A normalized plot of *i*(*t*) with respect to *i*_{ss} plotted versus *t*^{-1/2} (Figure S5) yielded a straight line with a slope of 0.210, an intercept of 0.834, and a *D*_{Gs} of 4.5 $\times 10^{-6}$ cm² s⁻¹. This value is close to that reported previously by Faraggi et al.¹⁶ in aqueous solution. From the steady-state current *i*_{ss} for a disk UME,

$$i_{ss} = 4nFD_{Gs}aC_{Gs}^*$$

(where *C*_{Gs}^{*} is the Gs concentration and *F* is the Faraday constant), an *n* value of 2 can be obtained from the steady-state voltammetric response shown in Figure 1. This indicates that the overall first EC oxidation wave of Gs in DMF is a two-electron process, as reported for Gs oxidation in aqueous solution.¹³

SECM was used to study the oxidation of Gs in DMF. In particular, we wanted to detect the radical cation Gs^{•+} generated in the primary electrooxidation step of Gs by SECM. On the basis of the present and previous studies,^{8,14} the overall electrooxidation of Gs in DMF is probably an ECE process, where the radical cation, Gs^{•+}, generated first, is unstable and quickly undergoes rapid deprotonation followed by fast loss of a second electron and subsequent hydration. This results in the formation of 8-oxo-Gs. To detect the unstable electrogenerated intermediate Gs^{•+}, Gs was oxidized at one electrode (tip) and detected at a second one (substrate) held in close proximity at a distance, *d*. Because of the

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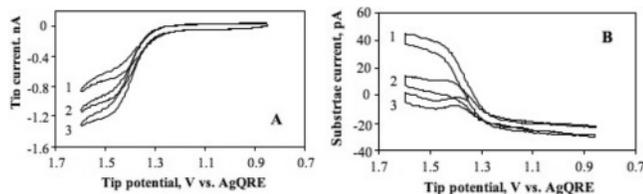


Figure 2. CVs for the oxidation of 2 mM guanosine in DMF/0.1M TBAPF₆ obtained at the tip (A) and substrate (B) electrodes. $E_S = 1.1$ V vs AgQRE. The scan rate of the tip potential was 20 mV/s. The distance between the tip and the substrate was (1) 0.15, (2) 0.3, and (3) 1 μm .

rapid deprotonation of Gs^{*+} , d must be small, so that Gs^{*+} can diffuse across the gap before reacting. Moreover, to decrease the background current in the substrate (since small, pA-level, currents must be detected), the substrate must also be small. This situation is different from most SECM experiments of this type and basically requires forming a nanogap between two μm -diameter electrodes, as shown in Figure S6. A CF-UME tip (10- μm diameter) was held in close proximity to a second tip of the same size immersed in the solution of interest. The tip potential was scanned in the region of Gs oxidation ($E_T = 0.85$ to 1.6 V versus an AgQRE). The substrate electrode was held at a potential ($E_S = 1.1$ V) where the tip-generated intermediate Gs^{*+} upon reaching the substrate surface is reduced back to Gs.

To form the nanogap by locating the small substrate electrode, SECM measurements were first performed in the substrate generation/tip collection (SG/TC) mode with Fc, which generates on oxidation a stable product, Fc^+ , as the redox mediator (2 mM ferrocene in DMF/0.1M TBAPF₆). The substrate potential was controlled such that Fc was oxidized to Fc^+ at a diffusion-controlled rate. A potential negative enough to reduce Fc^+ was applied to the tip, which was scanned in the vicinity of substrate surface (initially positioned about 5 μm away) to find the center of the 10- μm -diameter carbon substrate electrode, where the collection current is maximized. After the substrate electrode was found and the nanogap formed, the SECM Teflon cell was rinsed with DMF and 2 mM Gs in DMF/0.1M TBAPF₆ was added into the cell. SECM tip generation/substrate collection (TG/SC) experiments were then carried out. Figure 2 shows the CVs for the oxidation of 2 mM Gs obtained in this mode. When the distance between the tip and the substrate (d) was larger than 2 μm , no substrate collection current was observed, after correction for the nearly constant background of ~ -20 pA probably contributed from a small offset of the SECM instrument and a slight amount of oxidation of Gs at the potential of 1.1 V. When the tip was closer to the substrate ($d \leq 1$ μm), a substrate collection current was observed as shown in Figure 2, where the collection efficiency increased as the tip approached the substrate. We estimate the reaction layer thickness, μ , of the intermediate Gs^{*+} as ≤ 0.2 μm .¹⁷ The lifetime, τ , of Gs^{*+} can be estimated by the equation of $\tau \approx \mu^2/(2D_{\text{Gs}})$.¹⁰ Thus, the Gs^{*+} observed in this experiment has a $\tau \leq 40$ μs or equivalently it undergoes a first-order reaction with a rate constant, $k \geq 2.5 \times 10^4 \text{s}^{-1}$ in the solution studied. The reversible standard potential for the half reaction $\text{Gs}^{*+} + e = \text{Gs}$ can be obtained from the SECM

data at $d = 150$ nm, where the observed half-wave potential (0.89 V versus Fc^+/Fc) can be corrected for the effect of following reaction [i.e., a shift of $0.059 \log(1 + \mu k/m_R)$ or 0.02 V where $m_R = 4 D_R/\pi d$]¹⁸ to yield $E^\circ = 1.55$ V versus NHE. This can be compared to the E° estimated previously of 1.58 V versus NHE, from spectroscopic measurements in Ar-saturated aqueous solution of 2 mM Gs, 25 mM $\text{K}_2\text{S}_2\text{O}_8$, 0.1 mM 1,2,4-trimethoxybenzene, and 1 M 2-methyl-2-propanol.⁴

In conclusion, the SECM in a G/C nanogap configuration has been shown to be a useful technique for observing short-lived electrogenerated intermediates of Gs. The radical cation, Gs^{*+} , has been electrochemically detected for the first time, with an estimated lifetime of ≤ 40 μs . Because SECM measurements can be made under steady-state conditions, short time measurements are not needed. This technique should also allow electrode reactions of other nucleosides to be investigated that were previously not addressable by other EC techniques.

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Supporting Information Available: Additional experimental procedures and figures. This material is available free of charge via the Internet at <http://pubs.acs.org>.

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- The reaction layer thickness was estimated from the d value at which significant amount of Gs^{*+} was collected at the substrate after correction for its total background current (offset current of the SECM instrument plus a small amount of Gs oxidation) at 1.1 V bias. This d value was close to that for the case of curve 2 of Figure 2 ($d = 0.3$ μm).
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